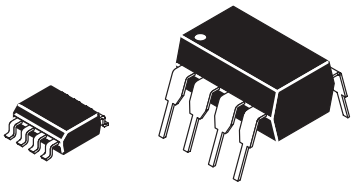


SLLS500A − MAY 2001 − REVISED MARCH 2005

# DIFFERENTIAL BUS TRANSCEIVER

## FEATURES

- **One-Fourth Unit Load Allows up to 128 Devices on a Bus**
- **ESD Protection for Bus Terminals:**
  - **±15-kV Human Body Model**
  - **±8-kV IEC61000-4-2, Contact Discharge**
  - **±15-kV IEC61000-4-2, Air-Gap Discharge**
- **Meets or Exceeds the Requirements of ANSI Standard TIA/EIA-485-A and ISO 8482: 1987(E)**
- **Controlled Driver Output-Voltage Slew Rates Allow Longer Cable Stub Lengths**
- **Designed for Signaling Rates† Up to 250-kbps**
- **Low Disabled Supply Current . . . 250 μA Max**
- **Thermal Shutdown Protection**
- **Open-Circuit Fail-Safe Receiver Design**
- **Receiver Input Hysteresis . . . 70 mV Typ**
- **Glitch-Free Power-Up and Power-Down Protection**

## APPLICATIONS

- **Utility Meters**
- **Industrial Process Control**
- **Building Automation**

## DESCRIPTION

The SN65LBC182 and SN75LBC182 are differential data line transceivers with a high level of ESD protection in the trade-standard footprint of the SN75176. They are designed for balanced transmission lines and meet ANSI standard TIA/EIA-485-A and ISO 8482. The SN65LBC182 and SN75LBC182 combine a 3-state, differential line driver and differential input line receiver, both of which operate from a single 5-V power supply. The driver and receiver have active-high and active-low enables, respectively, which can be externally connected together to function as a direction control.

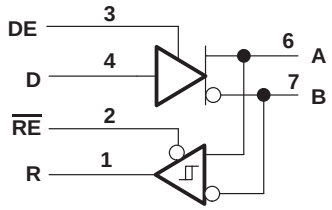
The driver outputs and the receiver inputs connect internally to form a differential input/output (I/O) bus port that is designed to offer minimum loading to the bus. This port operates over a wide range of common-mode voltage, making the device suitable for party-line applications. The device also includes additional features for party-line data buses in electrically noisy environment applications such as industrial process control or power inverters.

The SN75LBC182 and SN65LBC182 bus pins also exhibit a high input resistance equivalent to one-fourth unit load allowing connection of up to 128 similar devices on the bus. The high ESD tolerance protects the device for cabled connections. (For an even higher level of protection, see the SN65/75LBC184, literature number SLLS236.)

The differential driver design incorporates slew-rate-controlled outputs sufficient to transmit data up to 250 kbps. Slew-rate control allows longer unterminated cable runs and longer stub lengths from the main backbone than possible with uncontrolled voltage transitions. The receiver design provides a fail-safe output of a high level when the inputs are left floating (open circuit). Very low device supply current can be achieved by disabling the driver and the receiver.

The SN65LBC182 is characterized for operation from −40°C to 85°C, and the SN75LBC182 is characterized for operation from 0°C to 70°C.

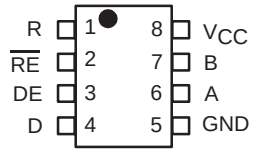
### functional block diagram



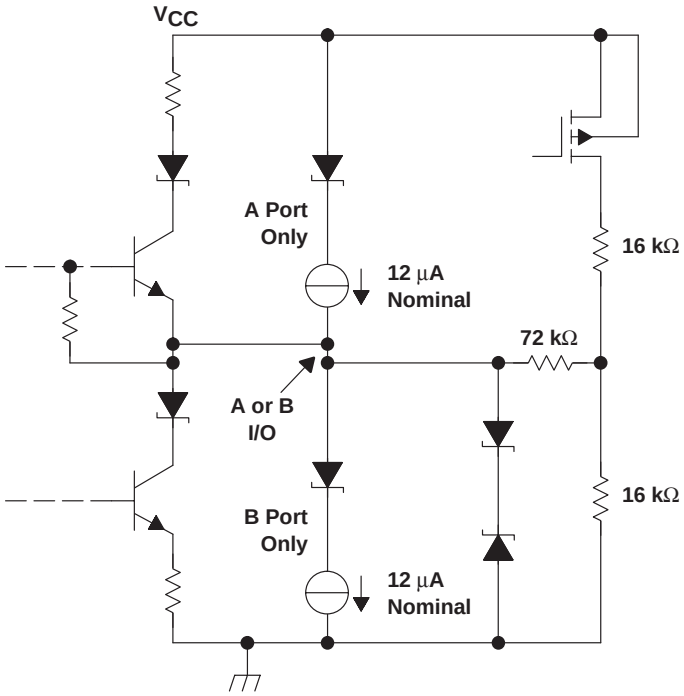

Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

†The signaling rate of a line, is the number of voltage transitions that are made per second expressed in the units bps (bits per second).

**SN65LBC182D (Marked as 6LB182)**
**SN75LBC182D (Marked as 7LB182)**
**SN65LBC182P (Marked as 65LBC182)**
**SN75LBC182P (Marked as 75LBC182)**
**(TOP VIEW)**




## schematic of inputs and outputs




## Function Tables

**DRIVER**

| INPUT D | ENABLE DE | OUTPUTS A | OUTPUTS B |
|---|---|---|---|
| H | H | H | L |
| L | H | L | H |
| X | L | Z | Z |
| Open | H | H | L |

**RECEIVER**

| DIFFERENTIAL INPUTS | ENABLE $\overline{RE}$ | OUTPUT R |
|---|---|---|
| $V_{ID} \geq 0.2$ V | L | H |
| -0.2V < $V_{ID}$ < 0.2 V | L | ? |
| $V_{ID} \leq$ -0.2 V | L | L |
| X | H | Z |
| Open | L | H |

**AVAILABLE OPTIONS**

| $T_A$ | PACKAGE | |
|---|---|---|
| | PLASTIC SMALL-OUTLINE† (JEDEC MS-012) | PLASTIC DUAL-IN-LINE PACKAGE (JEDEC MS-001) |
| 0°C to 70°C | SN75LBC182D | SN75LBC182P |
| −40°C to 85°C | SN65LBC182D | SN65LBC182P |

† Add R suffix for taped and reel.
† For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI web site at www.ti.com.

## absolute maximum ratings† over operating free−air temperature range unless otherwise noted

Supply voltage range, (see Note 1) $V_{CC}$ . . . . . −0.5 V to 7 V
Voltage range at any bus terminal (A or B) . . . . . −15 V to 15 V
Input voltage, $V_I$ (D, DE, R or $\overline{RE}$) . . . . . −0.3 V to 7 V
Receiver output current, $I_O$ . . . . . ±20 mA
Electrostatic discharge: Human body model (see Note 2) A, B, GND . . . . . 15 kV
All pins . . . . . 3 kV
Contact discharge (IEC61000-4-2) A, B, GND . . . . . 8 kV
Air discharge (IEC61000-4-2) A, B, GND . . . . . 15 kV
Continuous total power dissipation . . . . . See Dissipation Rating Table

† Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. All voltage values, except differential I/O bus voltages, are with respect to network ground terminal.
2. Tested in accordance with JEDEC Standard 22, Test Method A114-A.

**DISSIPATION RATING TABLE**

| PACKAGE | $T_A \le 25°C$ POWER RATING | DERATING FACTOR‡ ABOVE $T_A = 25°C$ | $T_A = 70°C$ POWER RATING | $T_A = 85°C$ POWER RATING |
|---|---|---|---|---|
| D | 725 mW | 5.8 mW/°C | 464 mW | 377 mW |
| P | 1150 mW | 9.2 mW/°C | 736 mW | 598 mW |

‡ This is the inverse of the junction-to-ambient thermal resistance when board-mounted and with no air flow.

NOTE: The maximum operating junction temperature is internally limited. Use the dissipation rating table to operate below this temperature

## recommended operating conditions

| | | MIN | NOM | MAX | UNIT |
|---|---|---|---|---|---|
| Supply voltage, $V_{CC}$ | | 4.75 | 5 | 5.25 | V |
| Voltage at any bus I/O terminal (separately or common mode) $V_I$ or $V_{IC}$ | | −7 | | 12 | V |
| High-level input voltage, $V_{IH}$ | D, DE, $\overline{RE}$ | 2 | | | V |
| Low-level input voltage, $V_{IL}$ | D, DE, $\overline{RE}$ | | | 0.8 | V |
| Differential input voltage, $V_{ID}$ (see Note 3) | | −12 | | 12 | V |
| Output current, $I_O$ | Driver | −60 | | 60 | mA |
| | Receiver | −8 | | 4 | mA |
| Operating free-air temperature, $T_A$ | SN65LBC182 | −40 | | 85 | °C |
| | SN75LBC182 | 0 | | 70 | °C |

NOTE 3: Differential input/output bus voltage is measured at the noninverting terminal A with respect to the inverting terminal B.

## driver electrical characteristics over recommended operating conditions

| PARAMETER | | | TEST CONDITIONS | | MIN | TYP† | MAX | UNIT |
|---|---|---|---|---|---|---|---|---|
| $V_{IK}$ | Input clamp voltage | | $I_I$ = −18 mA | | −1.5 | | | V |
| $V_O$ | Output voltage | | $I_O$ = 0 | | 0 | | $V_{CC}$ | V |
| $\|V_{OD}\|$ | Differential output voltage | | $R_L$ = 54 Ω, | See Figure 1 | 1.5 | 2.2 | $V_{CC}$ | V |
| | | | $V_{test}$ = −7 V to 12 V, | See Figure 2 | 1.5 | 2.2 | $V_{CC}$ | V |
| $\Delta V_{OD}$ | Change in magnitude of differential output voltage | | See Figure 1 | | −0.2 | | 0.2 | V |
| $V_{OC(SS)}$ | Steady-state common-mode output voltage | | | | 1 | | 3 | |
| $\Delta V_{OC(SS)}$ | Change in steady-state common-mode output voltage | | See Figures 1 and 4 | | −0.2 | | 0.2 | |
| $V_{OC(PP)}$ | Peak-to-peak change in common-mode output voltage during state transitions | | | | | 0.8 | | V |
| $I_{OZ}$ | High-impedance output current | | See receiver input currents | | | | | |
| $I_{IH}$ | High-level input current (D, DE) | | $V_I$ = 2.4 V | | | | 50 | µA |
| $I_{IL}$ | Low-level input current (D, DE) | | $V_I$ = 0.4 V | | −50 | | | µA |
| $I_{OS}$ | Short-circuit output current | | $V_O$ = −7 V to 12 V | | −250 | | 250 | mA |
| $I_{CC}$ | Supply current | SN75LBC182 | No load, DE at $V_{CC}$, | $\overline{RE}$ at $V_{CC}$ | | 12 | 25 | mA |
| | | SN65LBC182 | | | | 12 | 30 | |

† All typical values are at $V_{CC}$ = 5 V and $T_A$ = 25°C.

## driver switching characteristics over recommended operating conditions (unless otherwise noted)

| PARAMETER | | TEST CONDITIONS | | MIN | TYP | MAX | UNIT |
|---|---|---|---|---|---|---|---|
| $t_r$ | Differential output signal rise time | $R_L$ = 54 Ω, | $C_L$ = 50 pF, | 0.25 | 0.72 | 1.2 | µs |
| $t_f$ | Differential output signal fall time | See Figure 3 | | 0.25 | 0.73 | 1.2 | |
| $t_{PLH}$ | Propagation delay time, low-to-high-level output | | | | | 1.3 | |
| $t_{PHL}$ | Propagation delay time, high-to-low-level output | | | | | 1.3 | |
| $t_{sk(p)}$ | Pulse skew ($t_{PHL}$ − $t_{PLH}$) | | | | 0.075 | 0.15 | |
| $t_{PZH}$ | Output enable time to high level | $R_L$ = 110 Ω, | See Figure 5 | | | 3.5 | µs |
| $t_{PHZ}$ | Output disable time from high level | | | | | 3.5 | |
| $t_{PZL}$ | Output enable time to low level | $R_L$ = 110 Ω, | See Figure 6 | | | 3.5 | µs |
| $t_{PLZ}$ | Output disable time from low level | | | | | 3.5 | |

## receiver electrical characteristics over recommended operating conditions (unless otherwise noted)

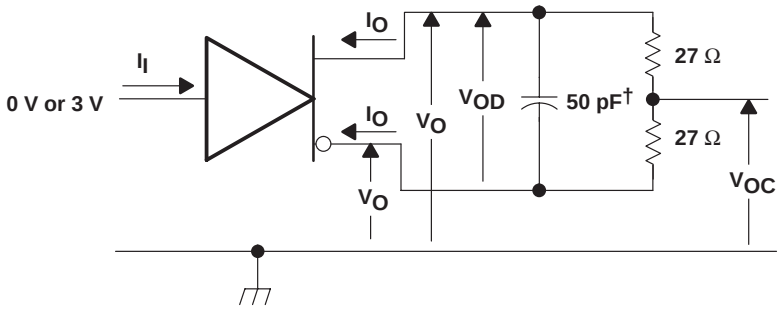
| PARAMETER | | TEST CONDITIONS | | MIN | TYP† | MAX | UNIT |
|---|---|---|---|---|---|---|---|
| $V_{IT+}$ | Positive-going input threshold voltage | | | | | 0.2 | V |
| $V_{IT-}$ | Negative-going input threshold voltage | | | −0.2 | | | V |
| $V_{hys}$ | Hysteresis voltage ($V_{IT+} - V_{IT-}$) | | | | 70 | | mV |
| $V_{IK}$ | Enable-input clamp voltage | $I_I$ = −18 mA | | −1.5 | | | V |
| $V_{OH}$ | High-level output voltage | $V_{ID}$ = 200 mV, $I_O$ = −8 mA, See Figure 7 | | 2.8 | | | V |
| $V_{OL}$ | Low-level output voltage | $V_{ID}$ = 200 mV, $I_O$ = 4 mA, See Figure 7 | | | | 0.4 | V |
| $I_{OZ}$ | High-impedance-state output current | $V_O$ = 0.4 to 2.4 V | | | | ±1 | µA |
| $I_I$ | Bus input current | $V_{IH}$ = 12 V, $V_{CC}$ = 5 V | Other input at 0 V | | | 250 | µA |
| | | $V_{IH}$ = 12 V, $V_{CC}$ = 0 V | | | | 250 | |
| | | $V_{IH}$ = −7 V, $V_{CC}$ = 5 V | | −200 | | | |
| | | $V_{IH}$ = −7 V, $V_{CC}$ = 0 V | | −200 | | | |
| $I_{IH}$ | High-level input current ($\overline{RE}$) | $V_{IH}$ = 2 V | | | | 50 | µA |
| $I_{IL}$ | Low-level input current ($\overline{RE}$) | $V_{IL}$ = 0.8 V | | −50 | | | µA |
| $I_{CC}$ | Supply current | No load | DE at 0 V, $\overline{RE}$ at 0 V | | | 3.5 | mA |
| | | | DE at 0 V, $\overline{RE}$ at $V_{CC}$ | | 175 | 250 | µA |

† All typical values are at $V_{CC}$ = 5 V and $T_A$ = 25°C.

## receiver switching characteristics over recommended operating conditions (unless otherwise noted)

| PARAMETER | | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|---|---|---|---|---|---|---|
| $t_r$ | Differential output signal rise time | $C_L$ = 50 pF, See Figure 7 | | 20 | | ns |
| $t_f$ | Differential output signal fall time | | | 20 | | |
| $t_{PLH}$ | Propagation delay time, low-to-high-level output | | | | 150 | |
| $t_{PHL}$ | Propagation delay time, high-to-low-level output | | | | 150 | |
| $t_{PZH}$ | Output enable time to high level | See Figure 8 | | | 100 | ns |
| $t_{PZL}$ | Output enable time to low level | | | | 100 | |
| $t_{PHZ}$ | Output disable time from high level | | | | 100 | ns |
| $t_{PLZ}$ | Output disable time from low level | | | | 100 | |
| $t_{sk(p)}$ | Pulse skew $\lvert t_{PHL} - t_{PLH} \rvert$ | | | | 50 | ns |

## PARAMETER MEASUREMENT INFORMATION




†Includes probe and jig capacitance

**Figure 1. Driver Test Circuit, $V_{OD}$ and $V_{OC}$ Without Common-Mode Loading**

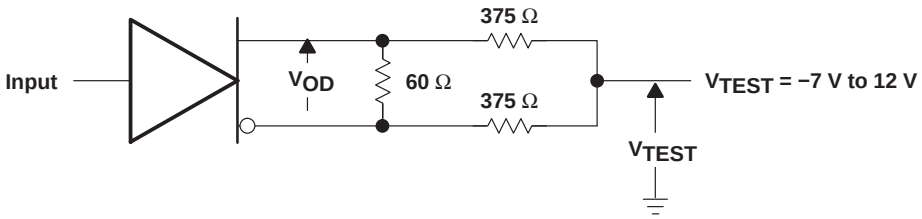
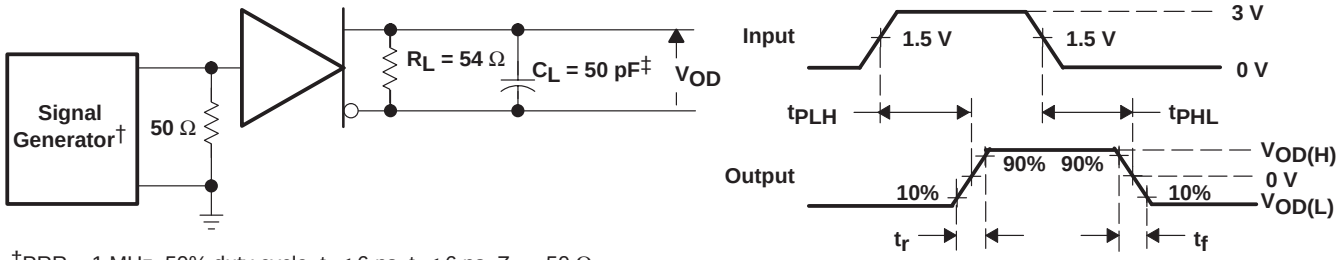



**Figure 2. Driver Test Circuit, $V_{OD}$ With Common-Mode Loading**




†PRR = 1 MHz, 50% duty cycle, $t_r$ < 6 ns, $t_f$ < 6 ns, $Z_O$ = 50 Ω
‡Includes probe and jig capacitance

**Figure 3. Driver Switching Test Circuit and Waveforms**

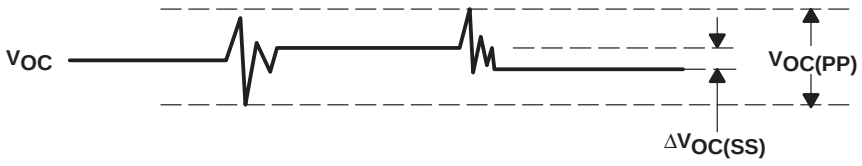
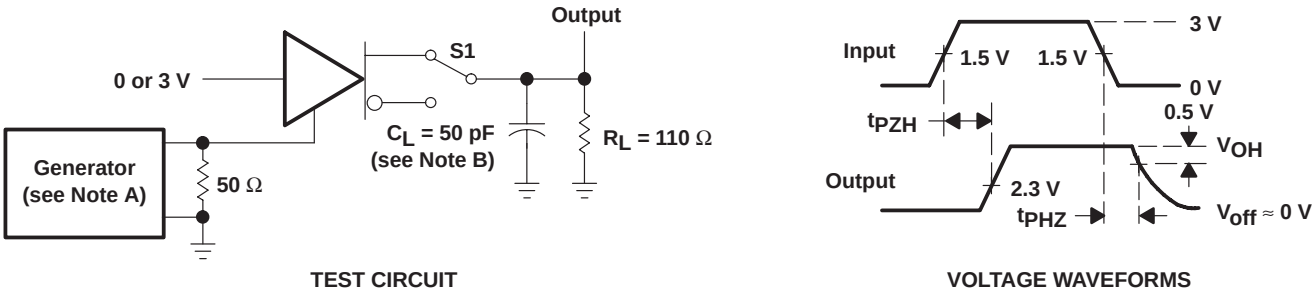



**Figure 4. $V_{OC}$ Definitions**

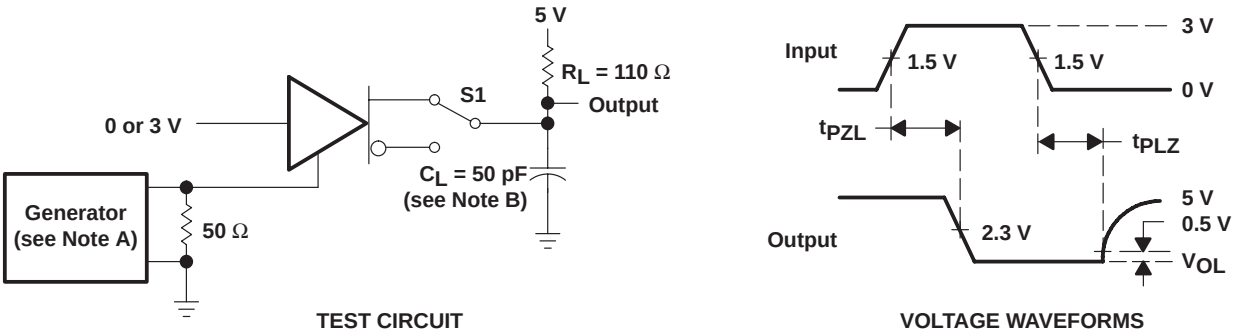
## PARAMETER MEASUREMENT INFORMATION




**TEST CIRCUIT** **VOLTAGE WAVEFORMS**

NOTES: A. The input pulse is supplied by a generator having the following characteristics: PRR = 1.25 kHz, 50% duty cycle, $t_r$ ≤ 10 ns, $t_f$ ≤ 10 ns, $Z_O$ = 50 Ω.
B. $C_L$ includes probe and jig capacitance.

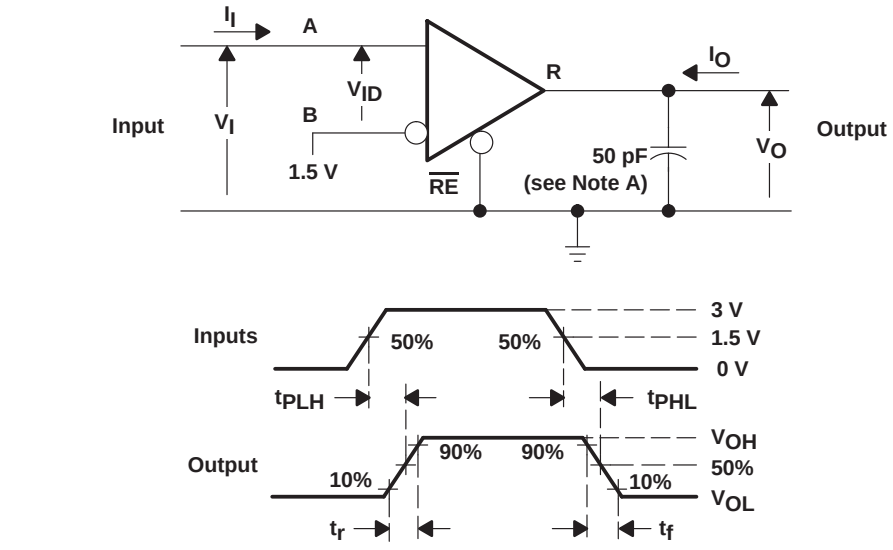
**Figure 5. Driver $t_{PZH}$ and $t_{PHZ}$ Test Circuit and Voltage Waveforms**




**TEST CIRCUIT** **VOLTAGE WAVEFORMS**

NOTES: A. The input pulse is supplied by a generator having the following characteristics: PRR = 1.25 kHz, 50% duty cycle, $t_r$ ≤ 10 ns, $t_f$ ≤ 10 ns, $Z_O$ = 50 Ω.
B. $C_L$ includes probe and jig capacitance.

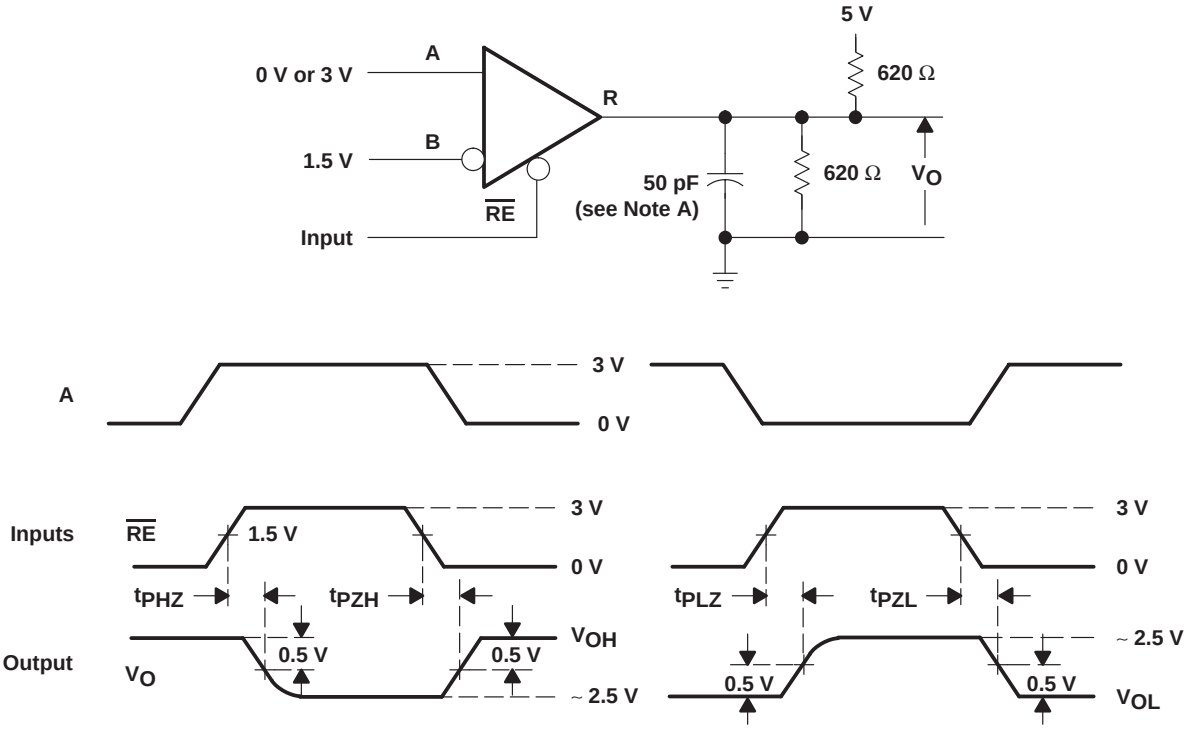
**Figure 6. Driver $t_{PZL}$ and $t_{PLZ}$ Test Circuit and Voltage Waveforms**




NOTE A: This value includes probe and jig capacitance (± 10%).

**Figure 7. Receiver $t_{PLH}$ and $t_{PHL}$ Test Circuit and Voltage Waveforms**

## PARAMETER MEASUREMENT INFORMATION




NOTE A: This value includes probe and jig capacitance (± 10%).

**Figure 8. Receiver $t_{PZL}$, $t_{PLZ}$, $t_{PZH}$, and $t_{PHZ}$ Test Circuit and Voltage Waveforms**

## TYPICAL CHARACTERISTICS

**DRIVER DIFFERENTIAL OUTPUT VOLTAGE vs TEMPERATURE**

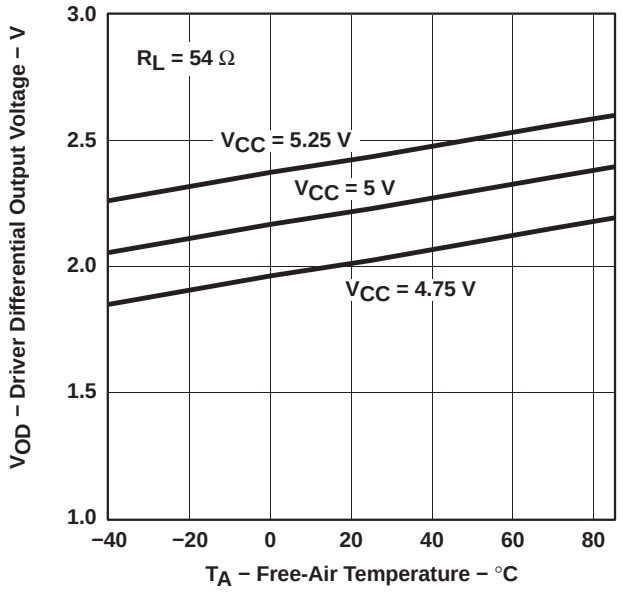



**Figure 9**

**DRIVER PROPAGATION DELAY TIME vs TEMPERATURE**

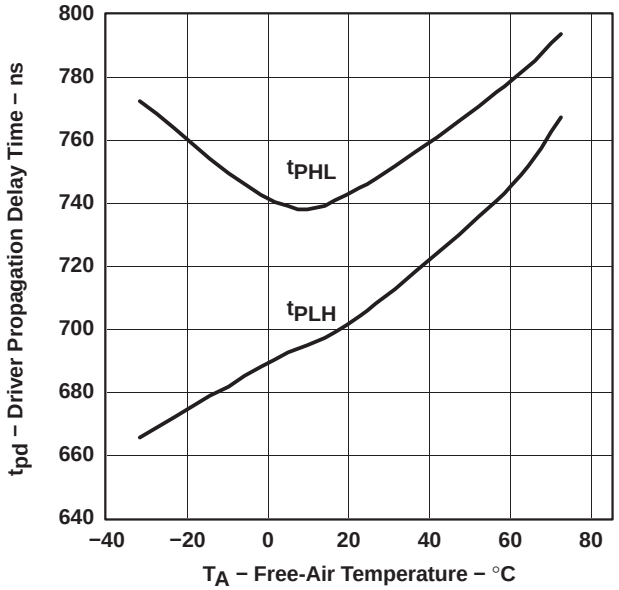



**Figure 10**

**DRIVER TRANSITION TIME vs TEMPERATURE**

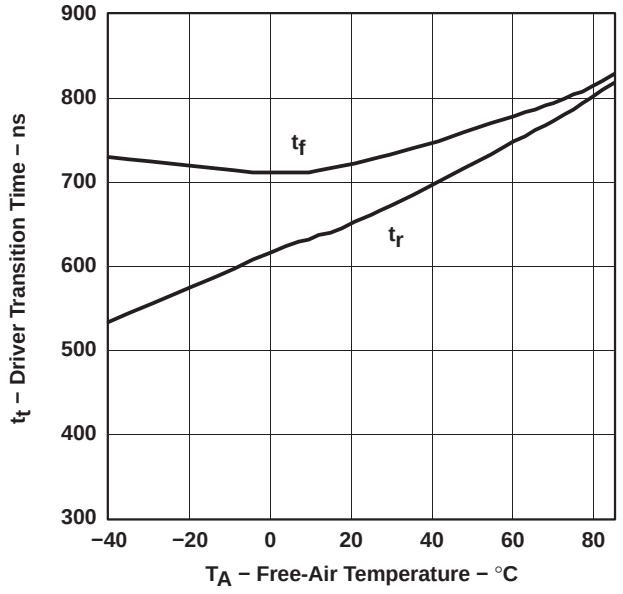



**Figure 11**

**DIFFERENTIAL OUTPUT VOLTAGE vs OUTPUT CURRENT**

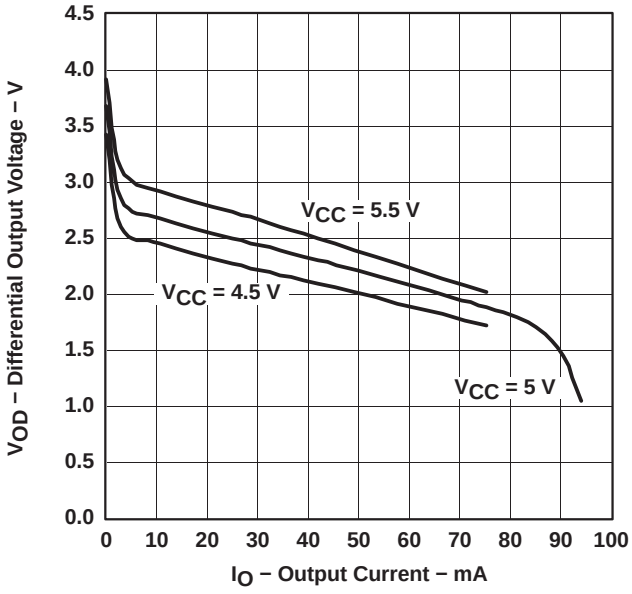



**Figure 12**

## TYPICAL CHARACTERISTICS

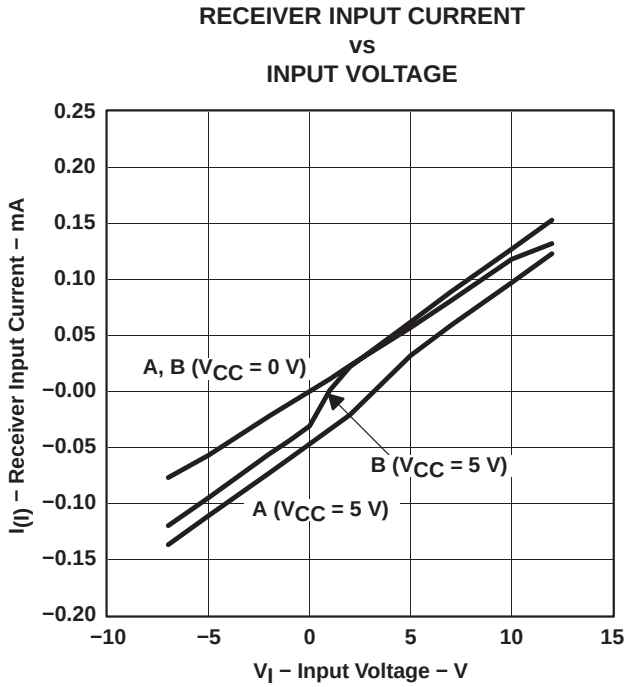
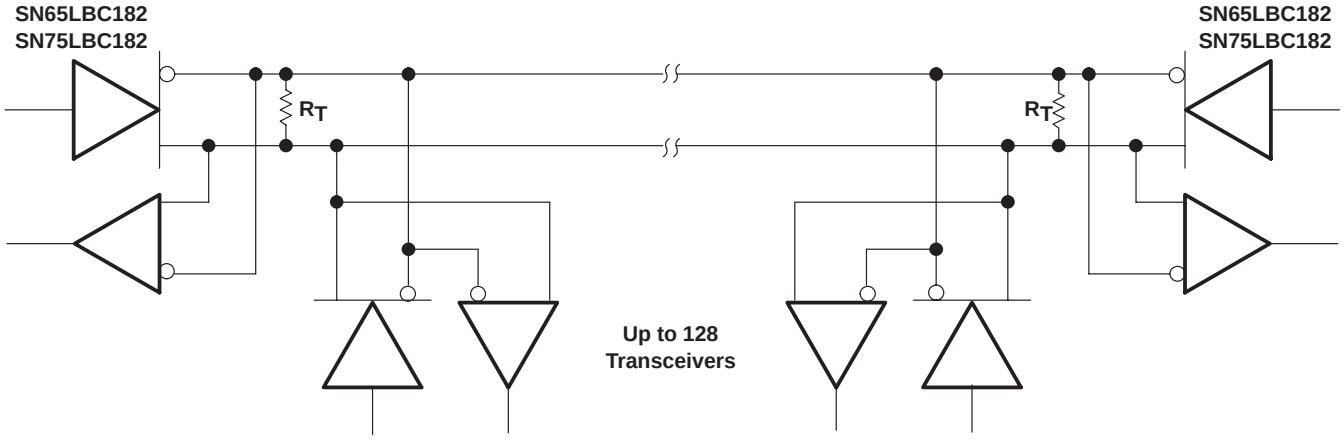



**Figure 13**

## APPLICATION INFORMATION




NOTE A: The line should be terminated at both ends in its characteristic impedance ($R_T = Z_O$). Stub lengths off the main line should be kept as short as possible.

**Figure 14. Typical Application Circuit**

## PACKAGING INFORMATION

| Orderable Device | Status (1) | Package Type | Package Drawing | Pins | Package Qty | Eco Plan (2) | Lead finish/ Ball material (6) | MSL Peak Temp (3) | Op Temp (°C) | Device Marking (4/5) | Samples |
|---|---|---|---|---|---|---|---|---|---|---|---|
| SN65LBC182D | ACTIVE | SOIC | D | 8 | 75 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 85 | 6LB182 | Samples |
| SN65LBC182DR | ACTIVE | SOIC | D | 8 | 2500 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 85 | 6LB182 | Samples |
| SN65LBC182DRG4 | ACTIVE | SOIC | D | 8 | 2500 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 85 | 6LB182 | Samples |
| SN65LBC182P | ACTIVE | PDIP | P | 8 | 50 | RoHS & Green | NIPDAU | N / A for Pkg Type | -40 to 85 | 65LBC182 | Samples |
| SN75LBC182D | ACTIVE | SOIC | D | 8 | 75 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | 0 to 70 | 7LB182 | Samples |
| SN75LBC182DG4 | ACTIVE | SOIC | D | 8 | 75 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | 0 to 70 | 7LB182 | Samples |
| SN75LBC182DR | ACTIVE | SOIC | D | 8 | 2500 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | 0 to 70 | 7LB182 | Samples |
| SN75LBC182P | ACTIVE | PDIP | P | 8 | 50 | RoHS & Green | NIPDAU | N / A for Pkg Type | 0 to 70 | 75LBC182 | Samples |

(1) The marketing status values are defined as follows:
**ACTIVE:** Product device recommended for new designs.
**LIFEBUY:** TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.
**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.
**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.
**OBSOLETE:** TI has discontinued the production of the device.

(2) **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".
**RoHS Exempt:** TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.
**Green:** TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

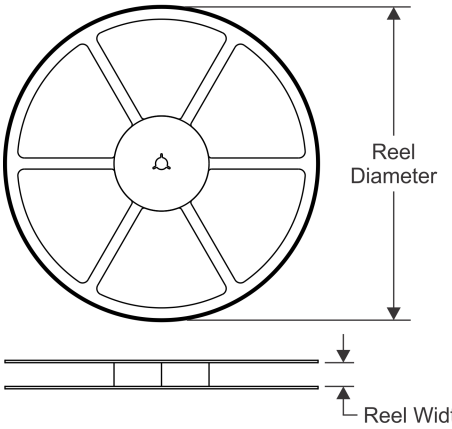
(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

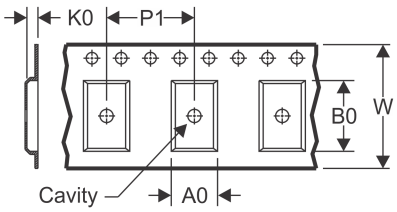
(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

## TAPE AND REEL INFORMATION

**REEL DIMENSIONS**

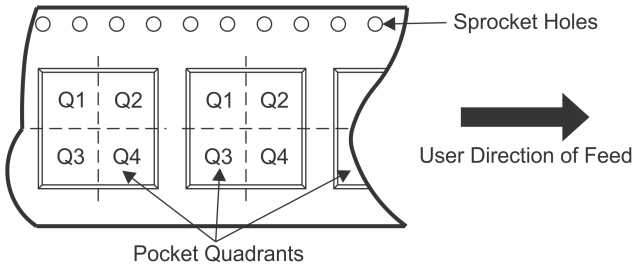



**TAPE DIMENSIONS**




| | |
|---|---|
| A0 | Dimension designed to accommodate the component width |
| B0 | Dimension designed to accommodate the component length |
| K0 | Dimension designed to accommodate the component thickness |
| W | Overall width of the carrier tape |
| P1 | Pitch between successive cavity centers |

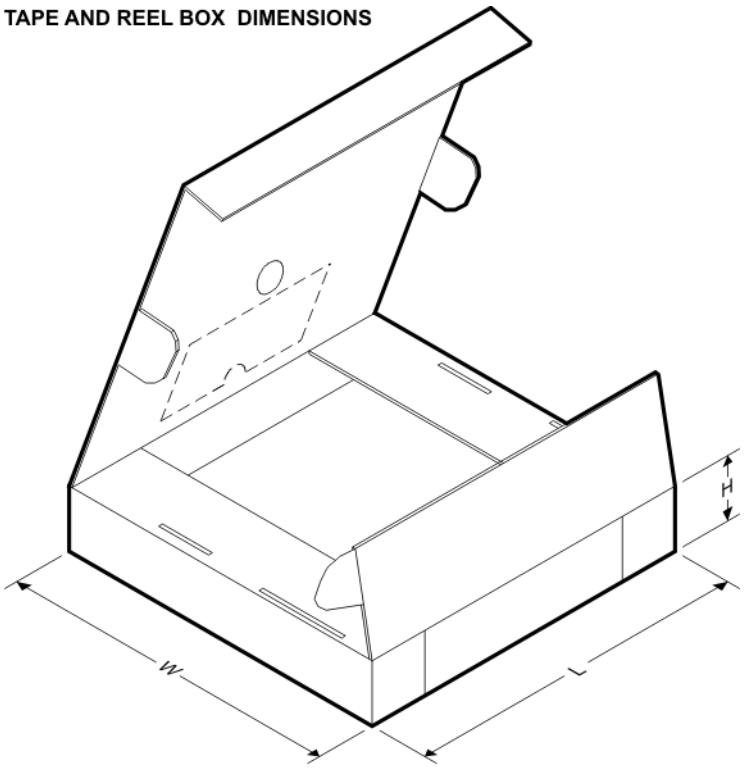
**QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE**




*All dimensions are nominal

| Device | Package Type | Package Drawing | Pins | SPQ | Reel Diameter (mm) | Reel Width W1 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P1 (mm) | W (mm) | Pin1 Quadrant |
|---|---|---|---|---|---|---|---|---|---|---|---|---|
| SN65LBC182DR | SOIC | D | 8 | 2500 | 330.0 | 12.4 | 6.4 | 5.2 | 2.1 | 8.0 | 12.0 | Q1 |
| SN75LBC182DR | SOIC | D | 8 | 2500 | 330.0 | 12.4 | 6.4 | 5.2 | 2.1 | 8.0 | 12.0 | Q1 |

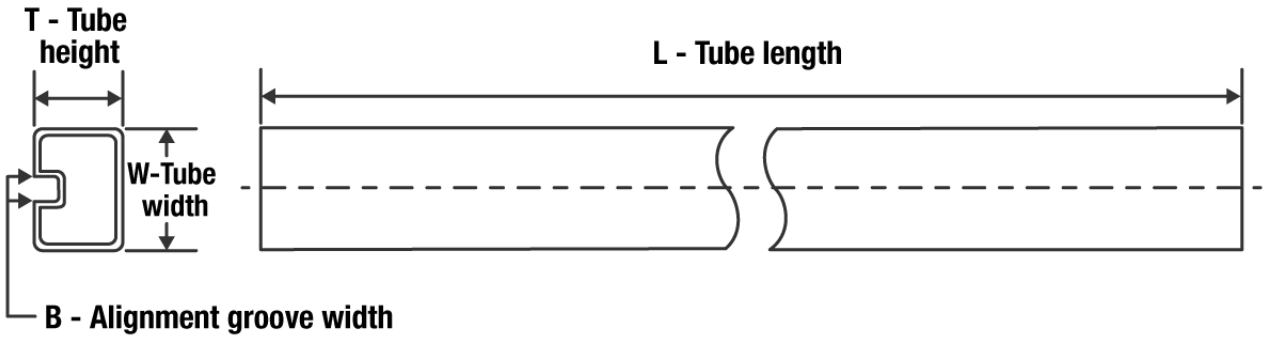
TAPE AND REEL BOX DIMENSIONS




*All dimensions are nominal

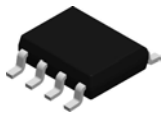
| Device | Package Type | Package Drawing | Pins | SPQ | Length (mm) | Width (mm) | Height (mm) |
|---|---|---|---|---|---|---|---|
| SN65LBC182DR | SOIC | D | 8 | 2500 | 340.5 | 336.1 | 25.0 |
| SN75LBC182DR | SOIC | D | 8 | 2500 | 340.5 | 336.1 | 25.0 |

## TUBE




*All dimensions are nominal

| Device | Package Name | Package Type | Pins | SPQ | L (mm) | W (mm) | T (µm) | B (mm) |
|---|---|---|---|---|---|---|---|---|
| SN65LBC182D | D | SOIC | 8 | 75 | 505.46 | 6.76 | 3810 | 4 |
| SN65LBC182D | D | SOIC | 8 | 75 | 507 | 8 | 3940 | 4.32 |
| SN65LBC182P | P | PDIP | 8 | 50 | 506 | 13.97 | 11230 | 4.32 |
| SN75LBC182D | D | SOIC | 8 | 75 | 507 | 8 | 3940 | 4.32 |
| SN75LBC182DG4 | D | SOIC | 8 | 75 | 507 | 8 | 3940 | 4.32 |
| SN75LBC182P | P | PDIP | 8 | 50 | 506 | 13.97 | 11230 | 4.32 |

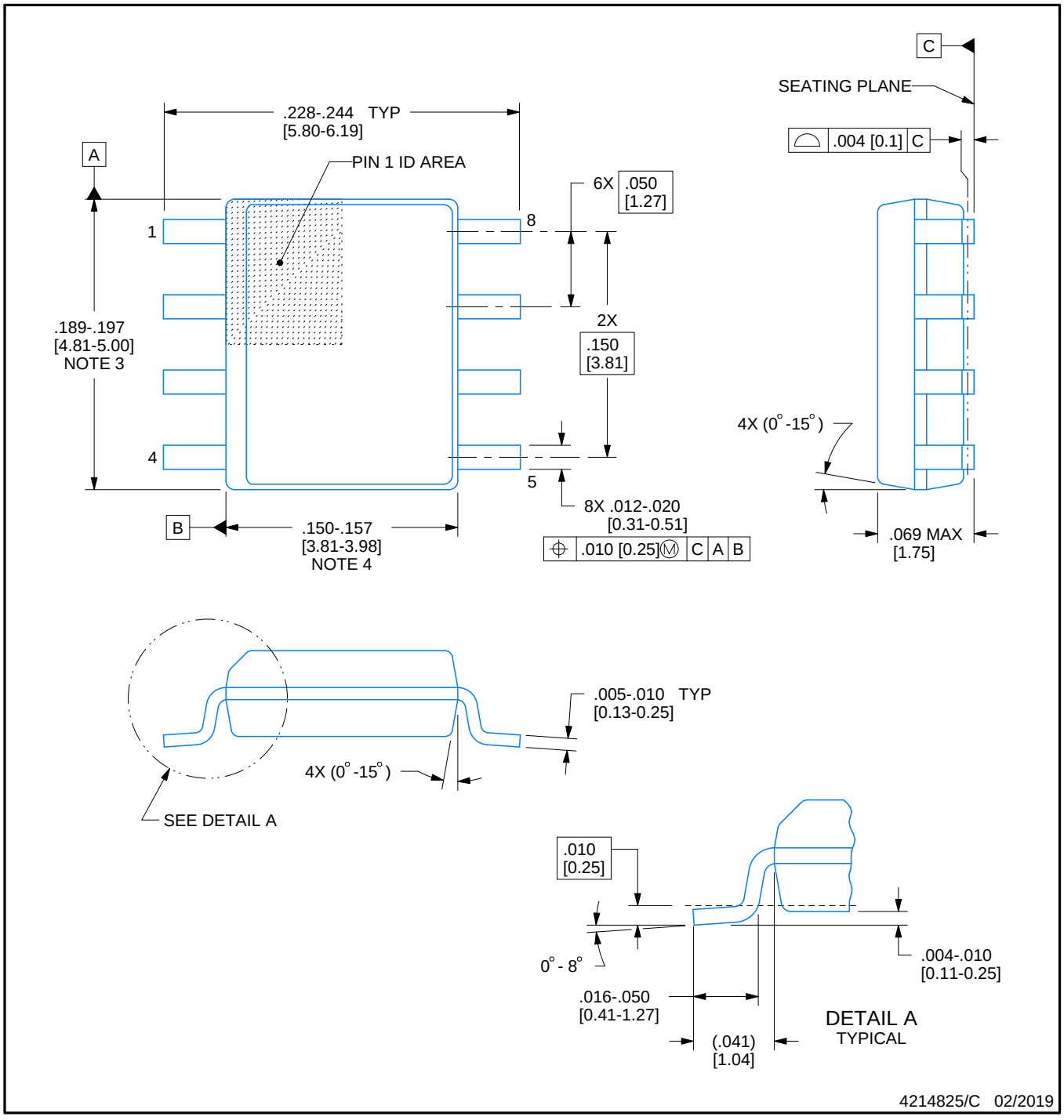


# PACKAGE OUTLINE

## D0008A

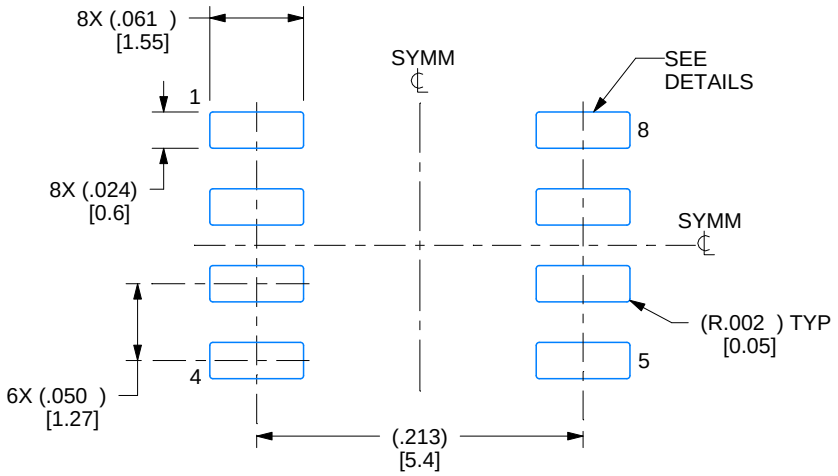
## SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT

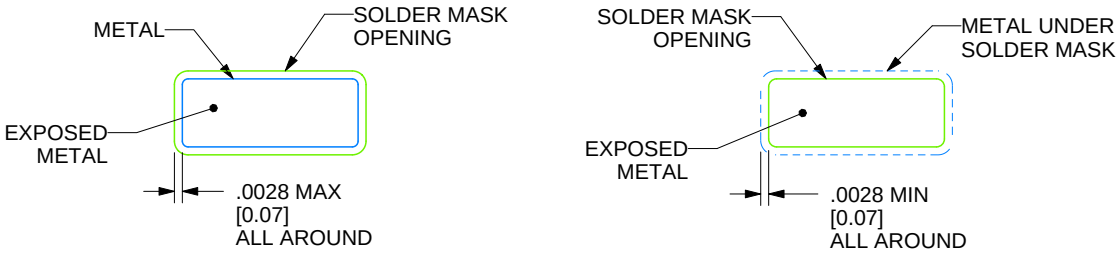



NOTES:

1. Linear dimensions are in inches [millimeters]. Dimensions in parenthesis are for reference only. Controlling dimensions are in inches. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 [0.15] per side.
4. This dimension does not include interlead flash.
5. Reference JEDEC registration MS-012, variation AA.




LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:8X




SOLDER MASK DETAILS

4214825/C 02/2019

NOTES: (continued)

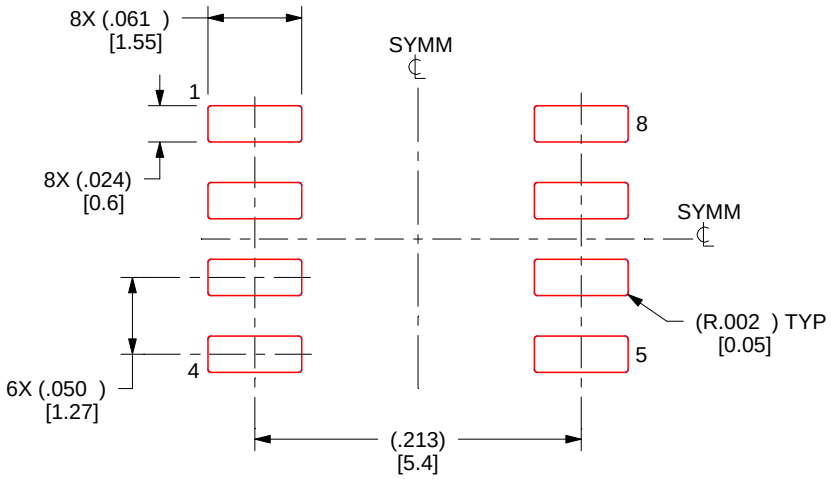
6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

# EXAMPLE STENCIL DESIGN

## D0008A

## SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT




SOLDER PASTE EXAMPLE
BASED ON .005 INCH [0.125 MM] THICK STENCIL
SCALE:8X

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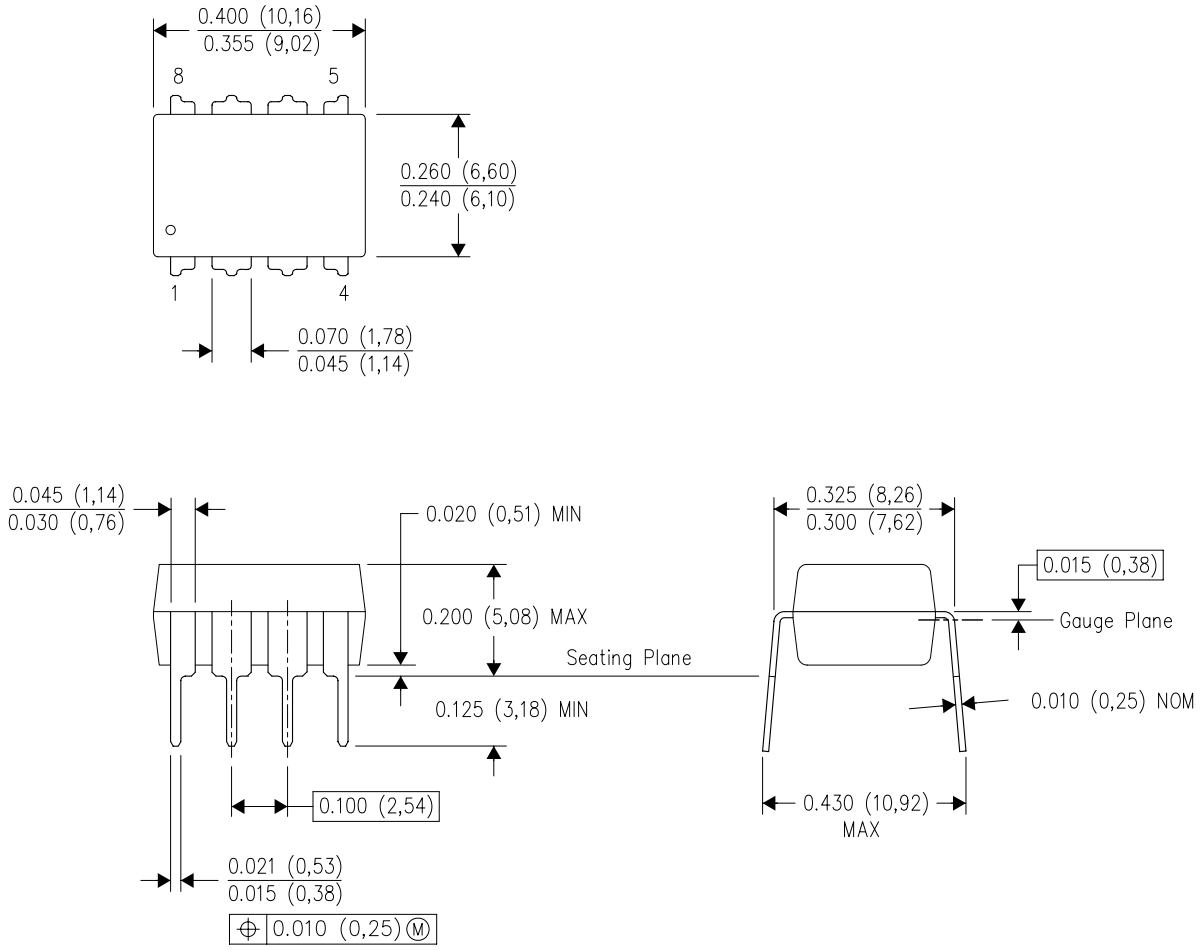
NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

P (R–PDIP–T8) PLASTIC DUAL–IN–LINE PACKAGE




NOTES:
A. All linear dimensions are in inches (millimeters).
B. This drawing is subject to change without notice.
C. Falls within JEDEC MS–001 variation BA.

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